

Vishay Siliconix

P-Channel 60-V (D-S), 175 °C MOSFET, Logic Level

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
- 60	0.170 at V _{GS} = - 10 V	- 10		
	0.280 at V _{GS} = - 4.5 V	- 8		

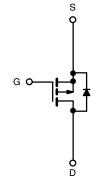
FEATURES

• TrenchFET[®] Power MOSFETs

• 175 °C Rated Maximum Junction Temperature



Ordering Information: SUD10P06-280L-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATING	S T _C = 25 °C, unle	ess otherwise no	ted		
Parameter Gate-Source Voltage		Symbol	Limit	Unit	
		V _{GS}	± 20	V	
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 25 °C		- 10		
Continuous Drain Current (1) = 130 C)	T _C = 100 °C		- 7		
Pulsed Drain Current		I _{DM}	- 20	А	
Continuous Source Current (Diode Conduction)		I _S	- 10		
Avalanche Current		I _{AS}	- 10	7	
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	5	mJ	
Marian Branchistica	T _C = 25 °C	P	37	14/	
Maximum Power Dissipation	T _A = 25 °C	P _D	2 ^a		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Junction-to-Ambient ^a	FR4 Board Mount	R _{thJA}	60	70		
	Free Air		120	120	140	°C/W
Junction-to-Case		R _{thJC}	3.7	4.0	1	

Notes:

a. Surface Mounted on FR4 board.

For SPICE model information via the Worldwide Web: http://www.vishay.com/www/product/spice.htm.

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Parameter	Symbol	Test Conditions		Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	V _{DS} = 0 V, I _D = - 250 μA - 60				V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0	- 2.0	- 3.0	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1		
	I _{DSS}	V_{DS} = - 60 V, V_{GS} = 0 V, T_{J} = 125 °C			- 50	μΑ	
		V_{DS} = - 60 V, V_{GS} = 0 V, T_{J} = 175 °C			- 150		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 10			Α	
b		V _{GS} = - 10 V, I _D = - 5 A		0.130	0.170		
		V_{GS} = - 10 V, I_D = - 5 A, T_J = 125 °C			0.31	Ω	
Drain-Source On-State Resistance ^b	R _{DS(on)}	V_{GS} = - 10 V, I _D = - 5 A, T _J = 175 °C			0.375		
		V _{GS} = - 4.5 V, I _D = - 2 A		0.210	0.280		
Forward Transconductance ^b	9 _{fs}	V _{DS} = - 15 V, I _D = - 5 A		6		S	
Dynamic		· · · · ·					
Input Capacitance	C _{iss}			635		pF	
Output Capacitance	C _{oss}	V_{DS} = - 25 V, V_{GS} = 0 V, f = 1 MHz		100			
Reverse Transfer Capacitance	C _{rss}			30			
Total Gate Charge	Qg			11.5	25	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 30 V, V_{GS} = - 10 V, I_D = - 10 A		3.5			
Gate-Drain Charge	Q _{gd}			2			
Turn-On Delay Time ^c	t _{d(on)}			9	20		
Rise Time ^c	t _r	V_{DD} = - 30 V, R_L = 3 Ω		16	20	- ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ 10 A, V_{GEN} = - 10 V, R_G = 2.5 Ω		17	30		
Fall Time ^c	t _f	1		19	35		
Source-Drain Diode Ratings and Cha	racteristics	$T_{C} = 25 \ ^{\circ}C^{a}$			ı I		
Pulsed Current	I _{SM}				- 20	А	
Forward Voltage ^b	V _{SD}	I _F = 10 A, V _{GS} = 0 V			- 1.3	V	
Reverse Recovery Time	t _{rr}	I _F = 10 A, dl/dt = 100 A/μs		50	80	ns	

Notes:

a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

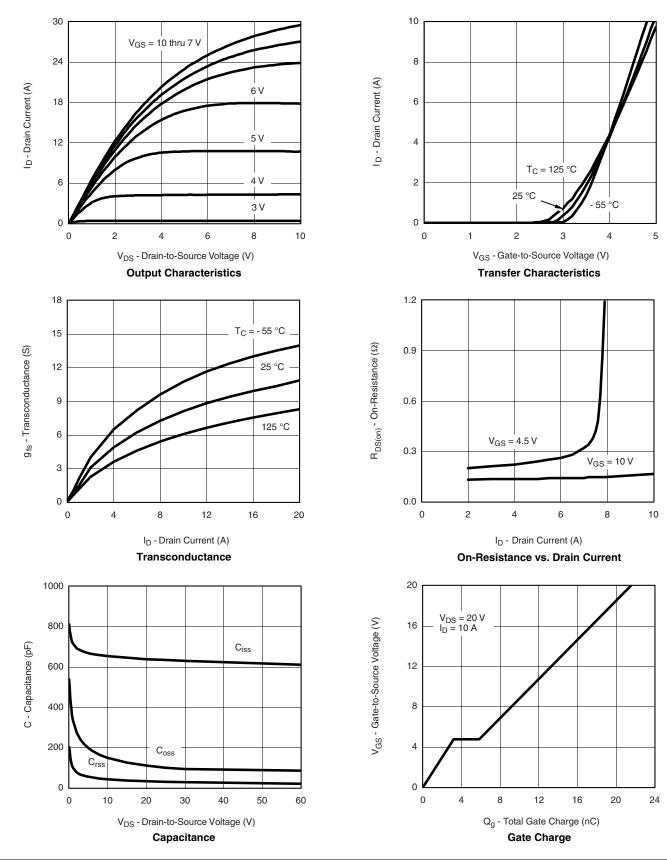
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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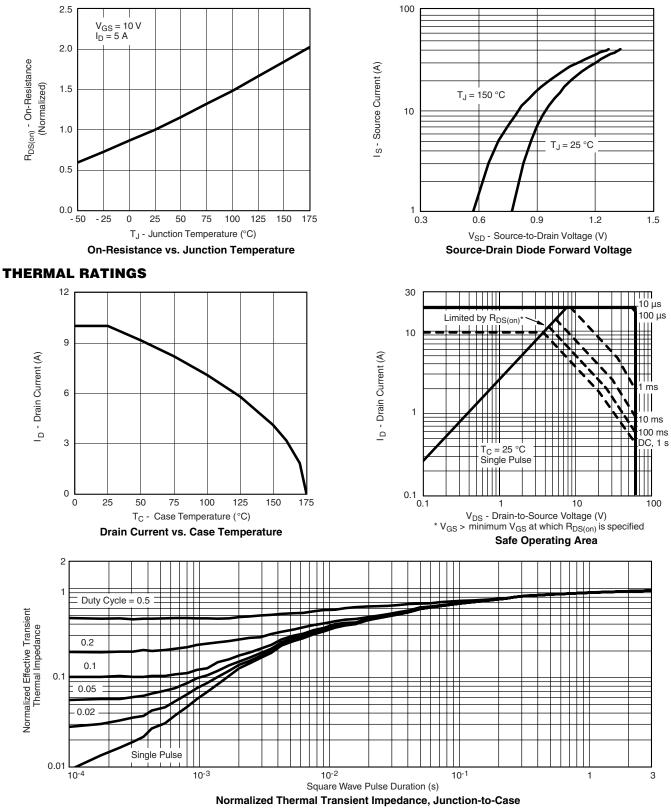
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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